

## 长春新产业光电技术有限公司

Changehun New Industries Optoelectronics Tech. Co., Ltd.

DATA SHEET

DPS-532-C/5~15mJ

## HIGH ENERGY DIODE PUMPED ALL-SOLID-STATE Q-SWITCHEDLASER

High energy diode pumped all solid state Q-switched laser at 532nm has the features of high single pulse energy, short pulse duration, and high peak power, which is widely used in LIF, LIBS, ICP-MS scientific research, laser processing, and so on.







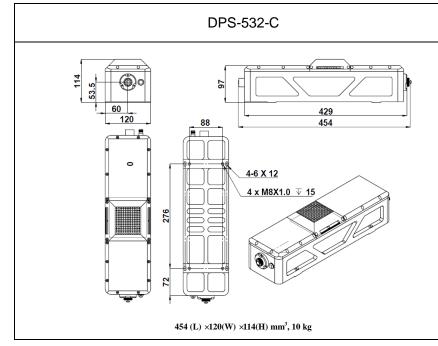


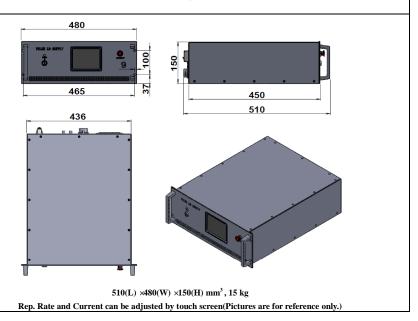
## SPECIFICATIONS

Wavelength (nm)	532±l		
Operating mode	Q-switched: EOM (Electro-optic modulation)		
Single pulse energy (mJ)	5@15Hz	10@15Hz	15@15Hz
Pulse duration (ns)	~10		•
Rep. rate (Hz)	10~40		
Energy stability	<3%, <5%		
Beam divergence, full angle (mrad)	~3		
Beam diameter (mm)	~2	~2.5	~3
Warm-up time (minutes)	<15		
Beam height from base plate (mm)	53.5		
Cooled method	Air cooled		
Operating temperature (°C)	15~35		
Power supply (220/110VAC)	PSU-DPS-Q-I(3U)		
Expected lifetime (pulses)	109		
Warranty period	1 year		
Available options	Other repetition rates; Jitter:~1ns(Sdev); Accessories		









PSU-DPS-Q-I (3U)